

METHOD OF FORMING STORAGE NODES IN A DRAM

Appl. No. : 09/851,580 Confirmation No. 3189
Applicant : Jiunn-Ren Hwang et al.
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TC/A.U. : 1795
Examiner : Ruggles, John S
Docket No. : NAUP0292USA
Customer No. : 27765

Commissioner for Patents
P.O. Box 1450
Alexandria VA 22313-1450

AMENDMENT

5 Sir:

In response to the Office action of October 21, 2008, please amend the above-identified application as follows:

Listing of the Claims begins on page 2 of this paper.

Amendments to the Drawings begin on page 3 of this paper.

10 **Remarks/Arguments** begin on page 4 of this paper.

An **Appendix** including amended drawing figures is attached following page 5 of this paper.